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## FAIRCHILD

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### FDV301N Digital FET , N-Channel

#### **General Description**

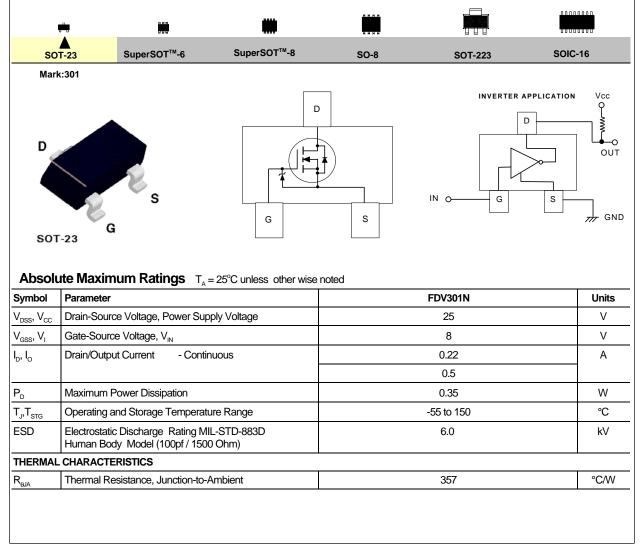
This N-Channel logic level enhancement mode field effect transistor is produced using Fairchild's proprietary, high cell density, DMOS technology. This very high density process is especially tailored to minimize on-state resistance. This device has been designed especially for low voltage applications as a replacement for digital transistors. Since bias resistors are not required, this one N-channel FET can replace several different digital transistors, with different bias resistor values.

#### Features

- 25 V, 0.22 A continuous, 0.5 A Peak.  $R_{DS(ON)} = 5 \Omega @ V_{GS} = 2.7 V$  $R_{DS(ON)} = 4 \Omega @ V_{GS} = 4.5 V.$
- Very low level gate drive requirements allowing direct operation in 3V circuits. V<sub>GS(th)</sub> < 1.06V.</li>

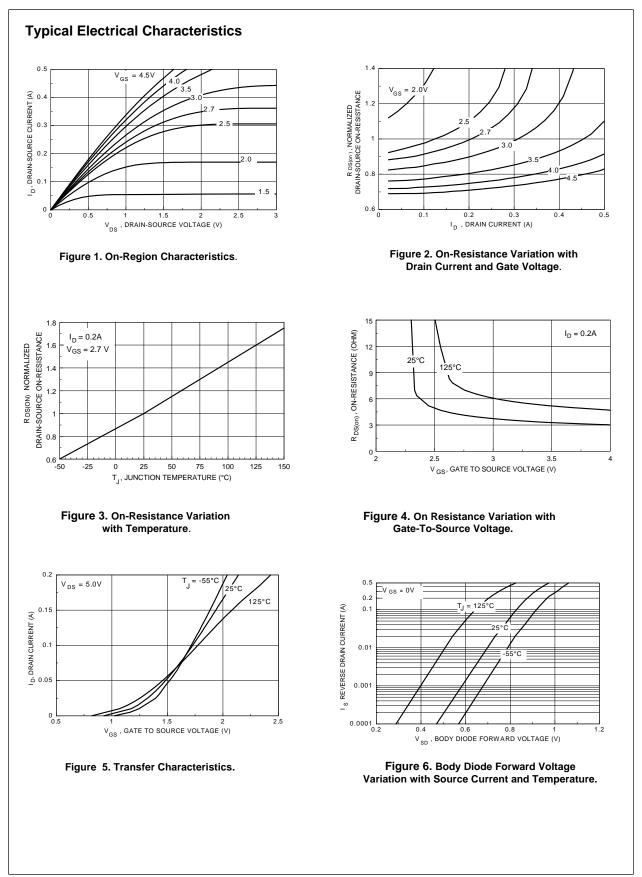
June 2009

- Gate-Source Zener for ESD ruggedness.
   >6kV Human Body Model
- Replace multiple NPN digital transistors with one DMOS FET.

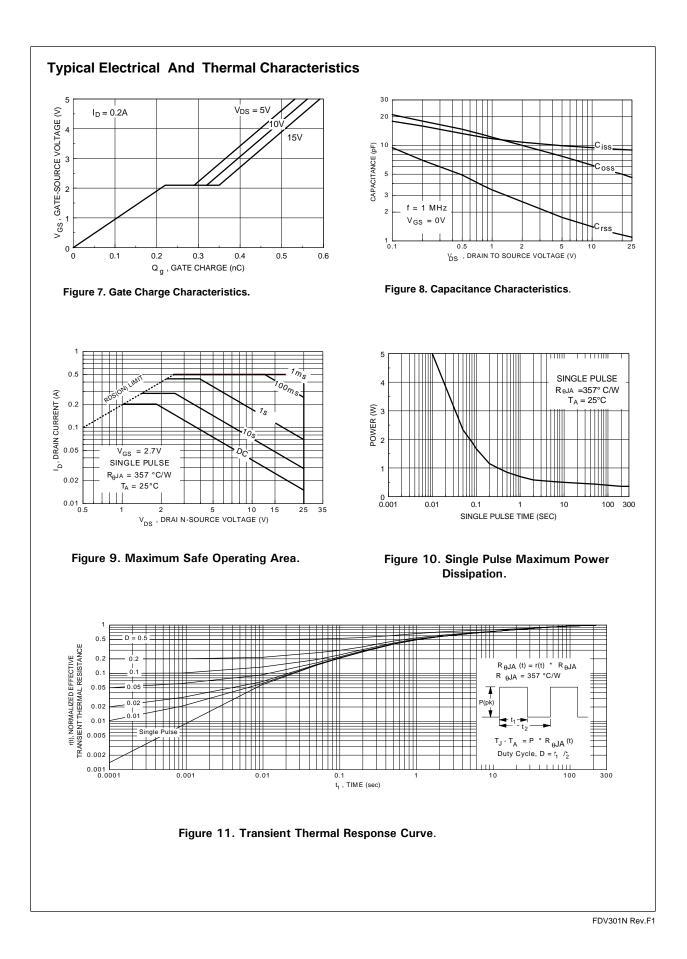


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Symbol	Parameter	Conditions	Min	Тур	Max	Units
I <sub>O (off)</sub>	Zero Input Voltage Output Current	$V_{cc} = 20 V, V_1 = 0 V$			1	μA
V <sub>I (off)</sub>	Input Voltage	$V_{cc} = 5 V, I_{o} = 10 \mu A$			0.5	V
V <sub>I (on)</sub>		$V_0 = 0.3 \text{ V}, \text{ I}_0 = 0.005 \text{ A}$	1			V
R <sub>O (on)</sub>	Output to Ground Resistance	$V_1 = 2.7 \text{ V}, \ I_0 = 0.2 \text{ A}$		4	5	Ω
Electric	al Characteristics (T <sub>A</sub> = 25 °C unless	s otherwise noted )				
Symbol	Parameter	Conditions	Min	Тур	Max	Units
OFF CHAF	ACTERISTICS					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = 250 \mu A$	25			V
$\Delta BV_{DSS}/\Delta T_{c}$	Breakdown Voltage Temp. Coefficient	$I_{\rm p}$ = 250 µA, Referenced to 25 °C		25		mV / °C
	Zero Gate Voltage Drain Current	$V_{DS} = 20 V, V_{GS} = 0 V$			1	μA
200		T <sub>1</sub> = 55°C			10	μA
GSS	Gate - Body Leakage Current	$V_{GS} = 8 V, V_{DS} = 0 V$			100	nA
	CTERISTICS (Note)					
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temp. Coefficient	$I_D = 250 \ \mu$ A, Referenced to $25 \ ^{\circ}C$		-2.1		mV/°C
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.70	0.85	1.06	V
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	$V_{GS} = 2.7 \text{ V}, I_{D} = 0.2 \text{ A}$		3.8	5	Ω
		T, =125°C		6.3	9	
		$V_{gs} = 4.5 \text{ V}, I_{p} = 0.4 \text{ A}$		3.1	4	
I <sub>D(ON)</sub>	On-State Drain Current	$V_{GS} = 2.7 \text{ V}, V_{DS} = 5 \text{ V}$	0.2			А
9 <sub>FS</sub>	Forward Transconductance	$V_{\rm DS} = 5 \text{ V}, \text{ I}_{\rm D} = 0.4 \text{ A}$		0.2		S
DYNAMIC (	CHARACTERISTICS			1	L	
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz		9.5		pF
C <sub>oss</sub>	Output Capacitance			6		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			1.3		pF
SWITCHING	G CHARACTERISTICS (Note)		•		•	•
t <sub>D(on)</sub>	Turn - On Delay Time	$V_{DD} = 6 \text{ V}, \text{ I}_{D} = 0.5 \text{ A},$ $V_{GS} = 4.5 \text{ V}, \text{ R}_{GEN} = 50 \Omega$		3.2	8	ns
t,	Turn - On Rise Time			6	15	ns
t <sub>D(off)</sub>	Turn - Off Delay Time			3.5	8	ns
t,	Turn - Off Fall Time			3.5	8	ns
С <sup>°</sup>	Total Gate Charge	$V_{DS} = 5 V, I_D = 0.2 A,$ $V_{GS} = 4.5 V$		0.49	0.7	nC
$Q_{gs}$	Gate-Source Charge			0.22		nC
Q <sub>gd</sub>	Gate-Drain Charge			0.07		nC
DRAIN-SO	JRCE DIODE CHARACTERISTICS AND MAXIMU	JM RATINGS	-	1	1	1
l <sub>s</sub>	Maximum Continuous Drain-Source Diode Fo	aximum Continuous Drain-Source Diode Forward Current			0.29	А
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 0.29 A$ (Note)		0.8	1.2	V



FDV301N Rev.F1





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